
DISCRETE POWER DIODES and THYRISTORS
DATA BOOK

INVERTER GRADE THYRISTORS

Hockey Puk Version

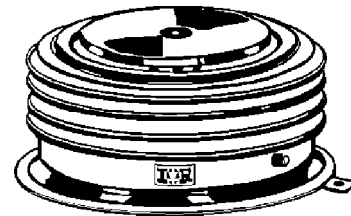
Features

- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)
- All diffused design
- Center amplifying gate
- Guaranteed high dV/dt
- Guaranteed high dI/dt
- High surge current capability
- Low thermal impedance
- High speed performance

515A

Typical Applications

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters



case style TO-200AC (B-PUK)

Major Ratings and Characteristics

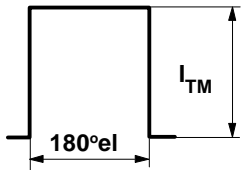
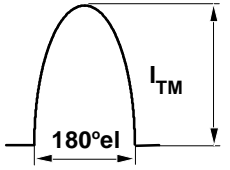
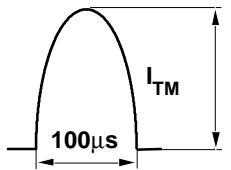
Parameters	ST303C..L	Units
$I_{T(AV)}$	515	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	995	A
@ T_{hs}	25	°C
I_{TSM} @ 50Hz	7950	A
@ 60Hz	8320	A
I^2t @ 50Hz	316	KA ² s
@ 60Hz	289	KA ² s
V_{DRM}/V_{RRM}	400 to 1200	V
t_q range (*)	10 to 30	μs
T_J	- 40 to 125	°C

(*) t_q = 10 to 20μs for 400 to 800V devices
 t_q = 15 to 30μs for 1000 to 1200V devices

ELECTRICAL SPECIFICATIONS**Voltage Ratings**

Type number	Voltage Code	$V_{\text{DRM}}/V_{\text{RRM}}$, maximum repetitive peak voltage V	V_{RSM} , maximum non-repetitive peak voltage V	$I_{\text{DRM}}/I_{\text{RRM}}$ max. @ $T_J = T_J \text{ max.}$ mA
ST303C..L	04	400	500	50
	08	800	900	
	10	1000	1100	
	12	1200	1300	

Current Carrying Capability

Frequency							Units
50Hz	1130	950	1800	1540	5660	4990	A
400Hz	1010	820	1850	1570	2830	2420	
1000Hz	680	530	1560	1300	1490	1220	
2500Hz	230	140	690	510	540	390	
Recovery voltage Vr	50	50	50	50	50	50	V
Voltage before turn-on Vd	V _{DRM}		V _{DRM}		V _{DRM}		
Rise of on-state current di/dt	50	50	-	-	-	-	A/µs
Heatsink temperature	40	55	40	55	40	55	°C
Equivalent values for RC circuit	10Ω / 0.47µF		10Ω / 0.47µF		10Ω / 0.47µF		

On-state Conduction

Parameter		ST303C..L	Units	Conditions		
$I_{T(AV)}$	Max. average on-state current @ Heatsink temperature	515 (190)	A	180° conduction, half sine wave double side (single side) cooled		
		55 (85)	°C			
$I_{T(RMS)}$	Max. RMS on-state current	995	A	DC @ 25°C heatsink temperature double side cooled		
I_{TSM}	Max. peak, one half cycle, non-repetitive surge current	7950		t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J \text{ max}$
		8320		t = 8.3ms	reapplied	
		6690		t = 10ms	100% V_{RRM}	
		7000		t = 8.3ms	reapplied	
I^2t	Maximum I^2t for fusing	316	KA²s	t = 10ms	No voltage	
		289		t = 8.3ms	reapplied	
		224		t = 10ms	100% V_{RRM}	
		204		t = 8.3ms	reapplied	
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	3160	KA²√s	t = 0.1 to 10ms, no voltage reapplied		

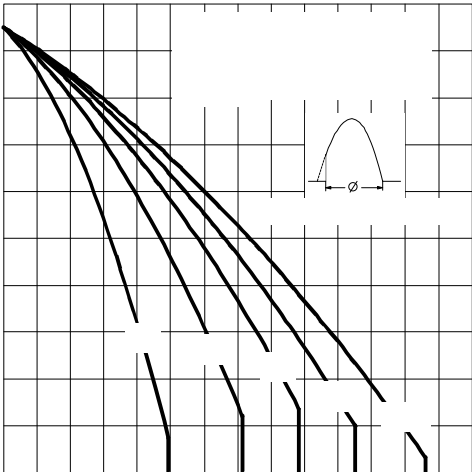


Fig. 3 - Current Ratings Characteristics

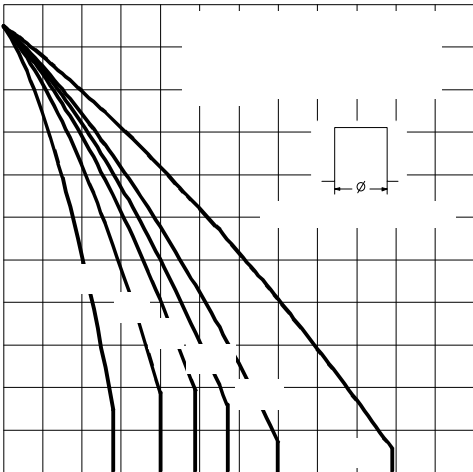


Fig. 4 - Current Ratings Characteristics

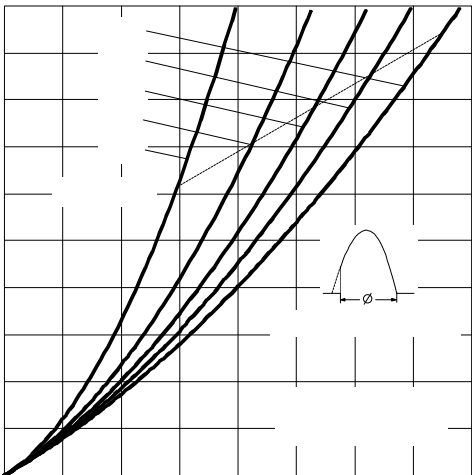


Fig. 5 - On-state Power Loss Characteristics

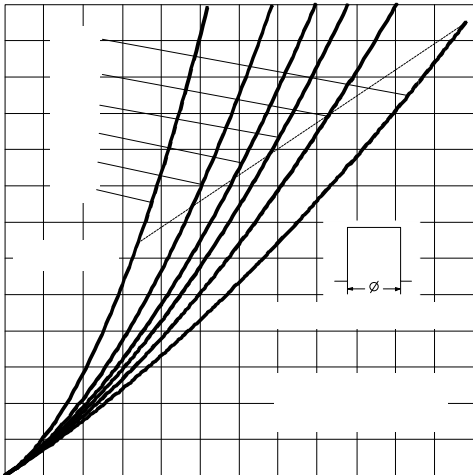


Fig. 6 - On-state Power Loss Characteristics

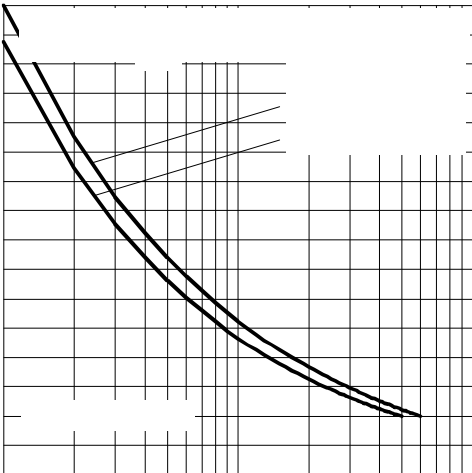


Fig. 7 - Maximum Non-repetitive Surge Current

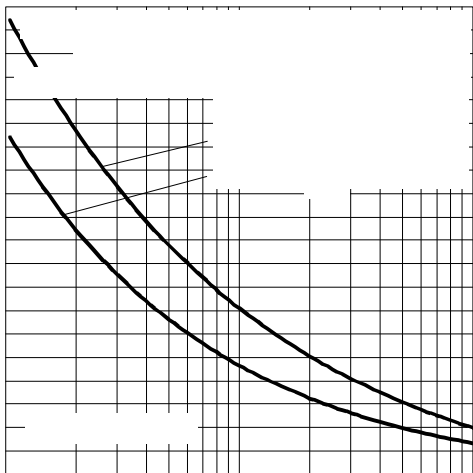


Fig. 8 - Maximum Non-repetitive Surge Current

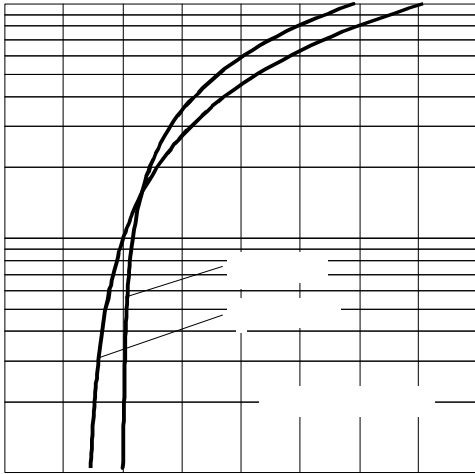


Fig. 9 - On-state Voltage Drop Characteristics

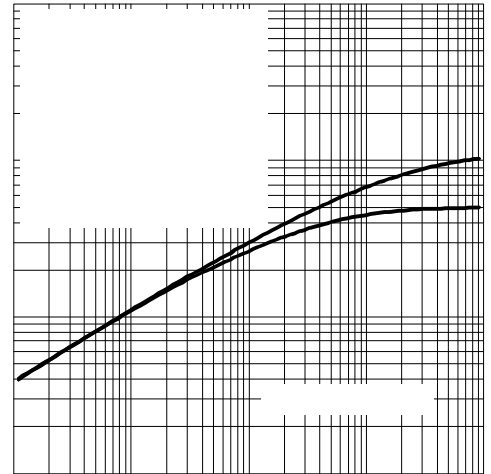
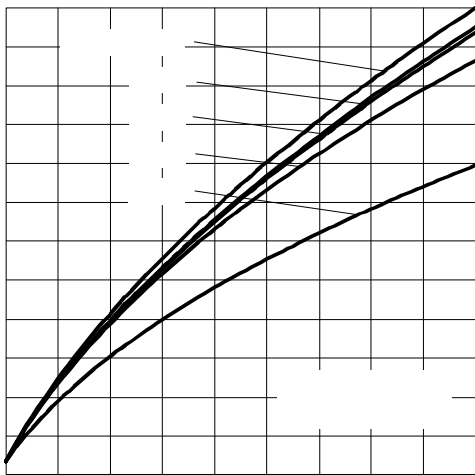
Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

Fig. 11 - Reverse Recovered Charge Characteristics

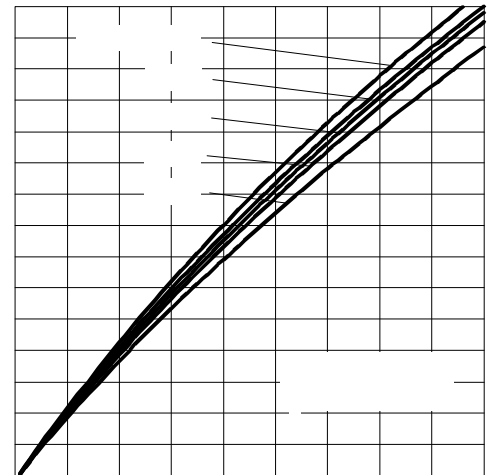


Fig. 12 - Reverse Recovery Current Characteristics

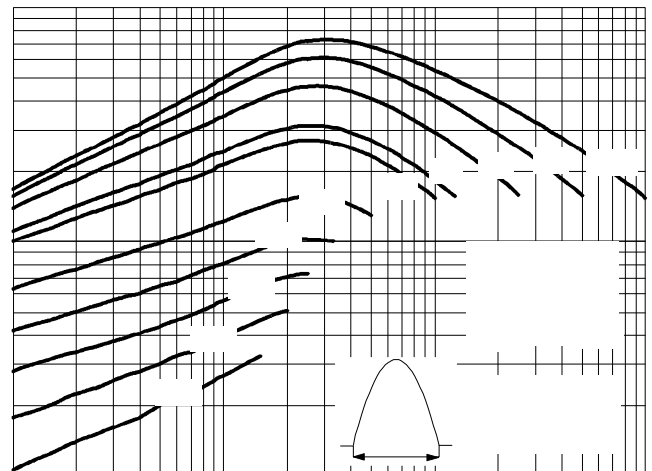
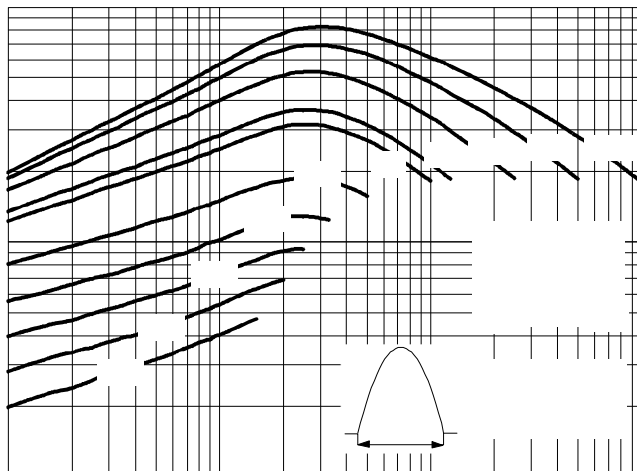


Fig. 13 - Frequency Characteristics

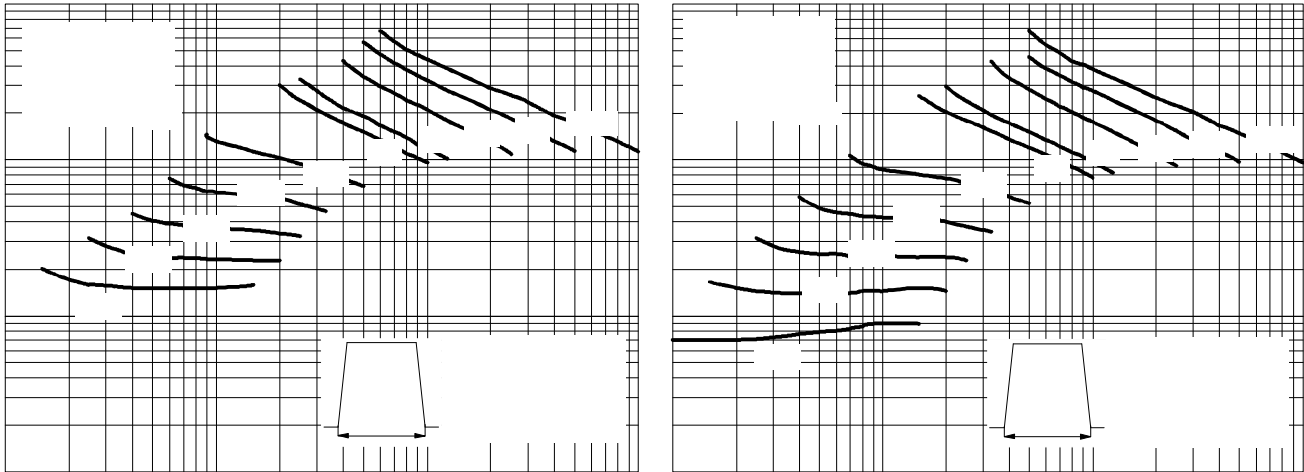


Fig. 14 - Frequency Characteristics

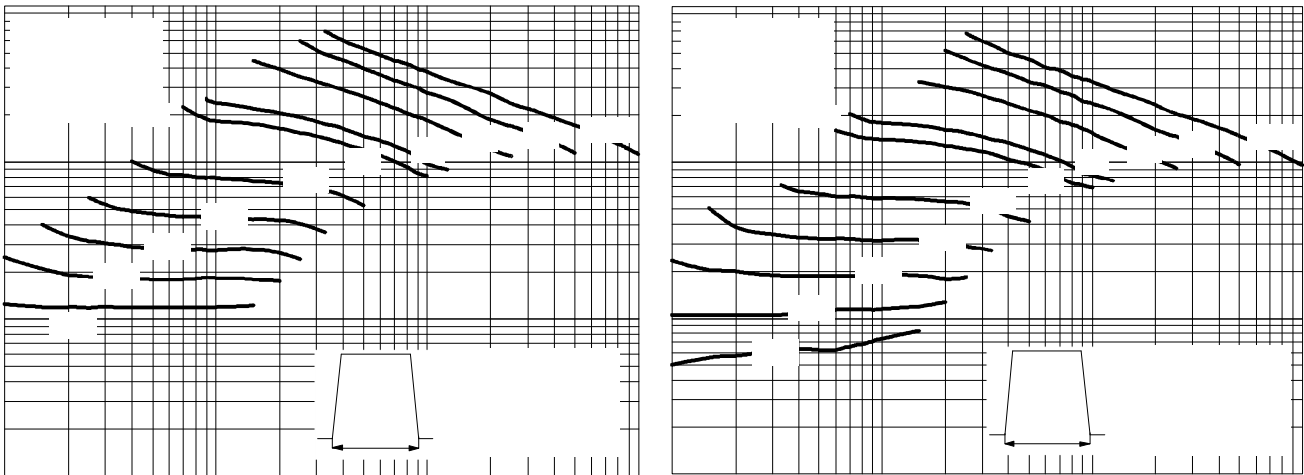


Fig. 15 - Frequency Characteristics

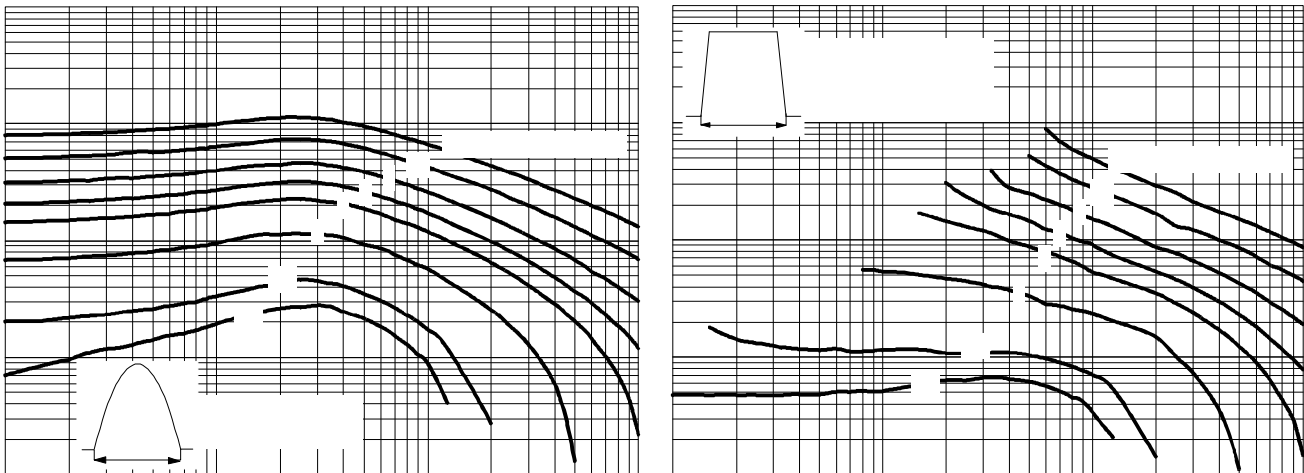


Fig. 16 - Maximum On-state Energy Power Loss Characteristics

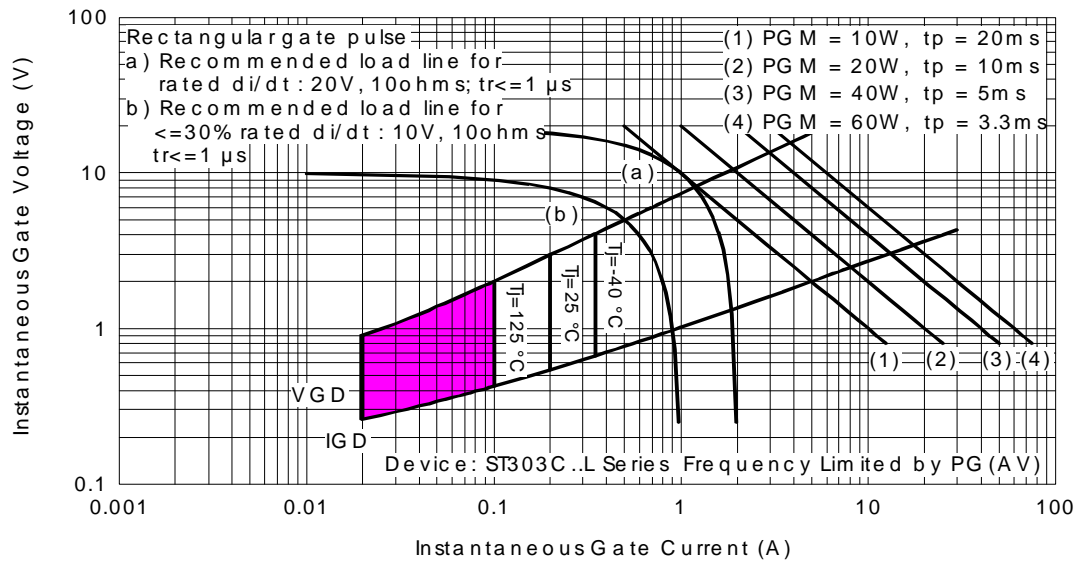


Fig. 17 - Gate Characteristics

On-state Conduction

Parameter	ST303C..L	Units	Conditions
V_{TM} Max. peak on-state voltage	2.16	V	$I_{TM} = 1255A$, $T_J = T_J \text{ max}$, $t_p = 10\text{ms}$ sine wave pulse
$V_{T(TO)1}$ Low level value of threshold voltage	1.44		$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
$V_{T(TO)2}$ High level value of threshold voltage	1.48		$(I > \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
r_{t1} Low level value of forward slope resistance	0.57	m Ω	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
r_{t2} High level value of forward slope resistance	0.56		$(I > \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
I_H Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$, $I_T > 30A$
I_L Typical atching current	1000		$T_J = 25^\circ\text{C}$, $V_A = 12V$, $R_a = 6\Omega$, $I_G = 1A$

Switching

Parameter	ST303C..L	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/ μs	$T_J = T_J \text{ max}$, $V_{DRM} = \text{rated } V_{DRM}$ $I_{TM} = 2 \times di/dt$
t_d Typical delay time	0.83	μs	$T_J = 25^\circ\text{C}$, $V_{DM} = \text{rated } V_{DRM}$, $I_{TM} = 50A$ DC, $t_p = 1\mu\text{s}$ Resistive load Gate pulse: 10V, 5 Ω source
t_q Max. turn-off time (*)	Min 10 Max 30		$T_J = T_J \text{ max}$, $I_{TM} = 550A$, commutating $di/dt = 40A/\mu\text{s}$ $V_R = 50V$, $t_p = 500\mu\text{s}$, dv/dt : see table in device code

(*) $t_q = 10$ to $20\mu\text{s}$ for 400 to 800V devices; $t_q = 15$ to $30\mu\text{s}$ for 1000 to 1200V devices.

Blocking

Parameter	ST303C..L	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ μs	$T_J = T_J \text{ max}$. linear to 80% V_{DRM} , higher value available on request
I_{RRM} Max. peak reverse and off-state leakage current I_{DRM}	50	mA	$T_J = T_J \text{ max}$, rated V_{DRM}/V_{RRM} applied

Triggering

Parameter	ST303C..L	Units	Conditions
P_{GM} Maximum peak gate power	60	W	$T_J = T_J \text{ max}$, $f = 50\text{Hz}$, $d\% = 50$
$P_{G(AV)}$ Maximum average gate power	10		
I_{GM} Max. peak positive gate current	10	A	$T_J = T_J \text{ max}$, $t_p \leq 5\text{ms}$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J \text{ max}$, $t_p \leq 5\text{ms}$
$-V_{GM}$ Maximum peak negative gate voltage	5		
I_{GT} Max. DC gate current required to trigger	200	mA	$T_J = 25^\circ\text{C}$, $V_A = 12V$, $R_a = 6\Omega$
V_{GT} Max. DC gate voltage required to trigger	3	V	
I_{GD} Max. DC gate current not to trigger	20	mA	$T_J = T_J \text{ max}$, rated V_{DRM} applied
V_{GD} Max. DC gate voltage not to trigger	0.25	V	

ST303C..L Series

Thermal and Mechanical Specification

Parameter	ST303C..L	Units	Conditions
T _J Max. operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJ-hs} Max. thermal resistance, junction to heatsink	0.11 0.05	K/W	DC operation single side cooled DC operation double side cooled
R _{thC-hs} Max. thermal resistance, case to heatsink	0.011 0.005	K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, ± 10%	9800 (1000)	N (Kg)	
wt Approximate weight	250	g	
Case style	TO - 200AC (B-PUK)		See Outline Table

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.012	0.010	0.008	0.008	K/W	T _J = T _J max.
120°	0.014	0.015	0.014	0.014		
90°	0.018	0.018	0.019	0.019		
60°	0.026	0.027	0.027	0.028		
30°	0.045	0.046	0.046	0.046		

Ordering Information Table

Device Code

ST	30	3	C	12	L	H	K	1	
1	2	3	4	5	6	7	8	9	10

- 1** - Thyristor
- 2** - Essential part number
- 3** - 3 = Fast turn off
- 4** - C = Ceramic Puk
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Rating Table)
- 6** - L = Puk Case TO-200AC (B-PUK)
- 7** - Reapplied dv/dt code (for t_q test condition)
- 8** - t_q code
- 9** - 0 = Eyelet term. (Gate and Aux. Cathode Unsoldered Leads)
 - 1 = Fast-on term. (Gate and Aux. Cathode Unsoldered Leads)
 - 2 = Eyelet term. (Gate and Aux. Cathode Soldered Leads)
 - 3 = Fast-on term. (Gate and Aux. Cathode Soldered Leads)
- 10** - Critical dv/dt:

None = 500V/μsec (Standard value)
L = 1000V/μsec (Special selection)

dv/dt - t _q combinations available						
	dv/dt (V/μs)	20	50	100	200	400
t _q (μs) up to 800V	10	CN	DN	EN	FN *	HN
	12	CM	DM	EM	FM	HM
	15	CL	DL	EL	FL *	HL
	20	CK	DK	EK	FK *	HK
t _q (μs) only for 1000/1200V	15	CL	--	--	--	--
	18	CP	DP	--	--	--
	20	CK	DK	EK	FK *	HK
	25	CJ	DJ	EJ	FJ *	HJ
	30	--	DH	EH	FH	HH

*Standard part number.
All other types available only on request.

Outline Table

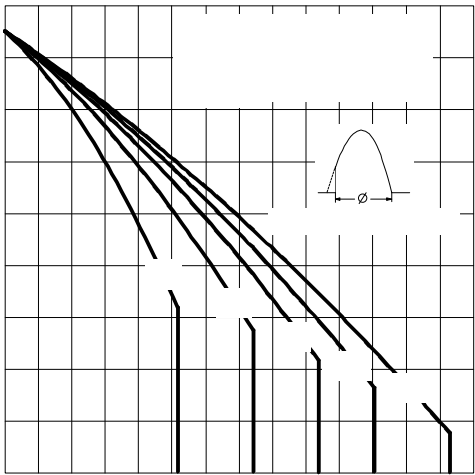
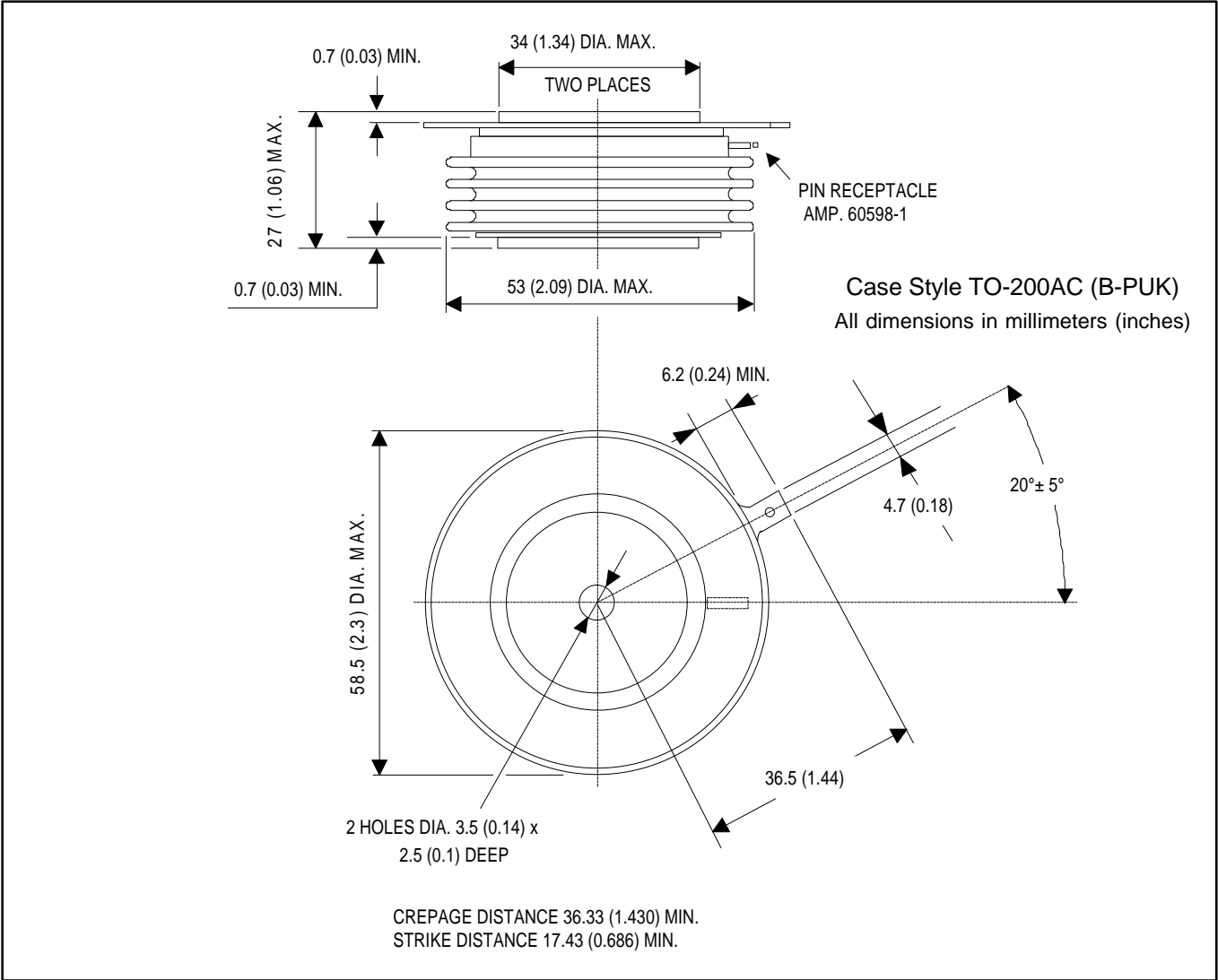


Fig. 1 - Current Ratings Characteristics

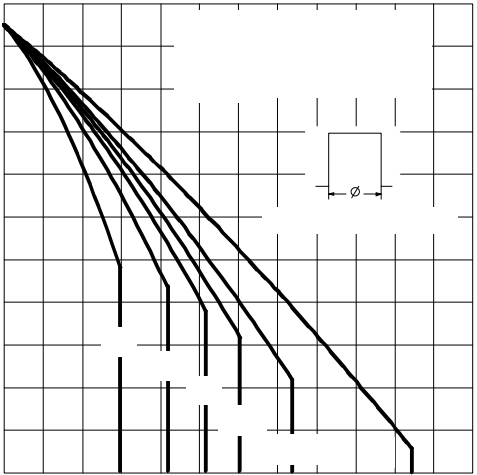


Fig. 2 - Current Ratings Characteristics